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Attorney's Docket No.: 07977-237002 / US 3559D1

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Hisashi Ohtani Art Unit : 2822
Serial No.: 09/621,943 Examiner : J.L. Brophy
Filed: July 24, 2000
Title : METHOD OF MANUFACTURING AN EL DISPLAY DEVICE

Commissioner for Patents
Washington, D.C. 20231

RESPONSE TO RESTRICTION REQUIREMENT

Responsive to the action mailed July 17, 2002, applicant elects the invention of Group 1 drawn to the embodiment of claims 1-13. The election is made without traverse.

PRELIMINARY AMENDMENT

Prior to examination, please amend the application as follows:

Add claims 20-23.

20. A method of manufacturing an EL display device, said method comprising the steps of:

forming an amorphous semiconductor film comprising $\text{Si}_x\text{Ge}_{1-x}$ ($0 < x < 1$) on an insulating surface;

applying a crystallization promoting material comprising a metal to the amorphous semiconductor film;

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02 FC:103
03 FC:126

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crystallizing the amorphous semiconductor film provided with said crystallization promoting material by heating.

21. The method according to claim 20 wherein said crystallization promoting material is applied to a selected portion of the amorphous semiconductor film.

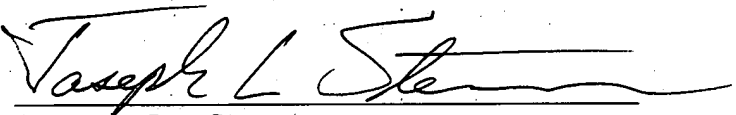
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22. The method according to claim 20 wherein said crystallization promoting material is applied by applying a solution containing said metal therein.

23. The method according to claim 20 wherein said metal is at least one selected from the group consisting of Fe, Co, Ni, Ru, Rh, Pd, Os, Ir, Pt, Cu and Au.

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Respectfully submitted,

Date: 8/19/2002


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